

DECLARATION OF CONTINUATION-IN-PART FOR PATENT APPLICATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor of the subject matter which is claimed and for which a patent is sought on the invention entitled: Method of Forming Integrated Circuitry and Method of Forming Shallow Trench Isolation in a Semiconductor Substrate, the specification of which is attached hereto.

This application in part discloses and claims subject matter disclosed in my earlier filed pending application, "Method and Composition for Plasma Etching of a Self-Aligned Contact Opening" Serial No. 09/752,685, filed January 3, 2001;

I hereby state that I have reviewed and understand the contents of the above identified specification, including the claims.

I hereby claim benefit under Title 35, United States Code, §120 in connection with said earlier filed application;

I acknowledge the duty to disclose information known to me to be material to patentability as defined in Title 37, Code of Federal Regulations §1.56, including any such information which became available between the filing date of the prior application and the national or PCT international filing date of this application.

As to the subject matter of this application, which is common to said earlier application, I do not know and do not believe that the same was ever known or used in the United States of America before my invention thereof or

patented or described in any printed publication in any country before my invention thereof, or more than one year prior to said earlier application, or in public use or on sale in the United States of America more than one year prior to said earlier application;

The common subject matter has not been patented or made the subject of an inventor's certificate issued before the date of said earlier application in any country foreign to the United States of America on an application filed by me or my legal representatives or assigns more than twelve months prior to said earlier application; and

As to applications for patents or inventor's certificate on the common subject matter filed in any country foreign to the United States of America, prior to said earlier application by me or my legal representatives or assigns, I hereby claim foreign priority benefits under Title 35, United States Code, §119 of any foreign application(s) for patent or inventor's certificate listed below and have also identified below any foreign application for patent or inventor's certificate having a filing date before that of the application on which priority is claimed:

PRIOR FOREIGN APPLICATION(S)

No such applications have been filed.

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such

willful false statement may jeopardize the validity of the application or any patent issued therefrom.

* * * * *

Full name of inventor: Shane J. Trapp

Inventor's Signature: Shane J. Trapp

Date: 7/25/01

Residence: Boise, Idaho

Citizenship: United States

Post Office Address: 1760 E. Victory
Boise, Idaho 83706

* * * * *

09920978-080101

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. Unassigned
Filing Date Herewith
Inventor Shane J. Trapp
Assignee Micron Technology, Inc.
Group Art Unit Unassigned
Examiner Unassigned
Attorney's Docket No. MI22-1674
Title: Method of Forming Integrated Circuitry and Method of Forming Shallow
Trench Isolation in a Semiconductor Substrate

**POWER OF ATTORNEY BY ASSIGNEE AND
CERTIFICATE BY ASSIGNEE UNDER 37 CFR § 3.73(b)**

To: Assistant Commissioner for Patents
Washington, D.C. 20231

Sir:

MICRON TECHNOLOGY, INC., the Assignee of the entire right, title and
interest in the above-identified patent application by assignment attached hereto,
hereby appoints the attorneys and agents of the firm of **WELLS, ST. JOHN,
ROBERTS, GREGORY & MATKIN P.S.**, listed as follows:

David P. Roberts	Reg. No. 23,032
Randy A. Gregory	Reg. No. 30,386
Mark S. Matkin	Reg. No. 32,268
James L. Price	Reg. No. 27,376
Deepak Malhotra	Reg. No. 33,560
Mark W. Hendricksen	Reg. No. 32,356
David G. Latwesen	Reg. No. 38,533
George G. Grigel	Reg. No. 31,166
Keith D. Grzelak	Reg. No. 37,144
James D. Shaurette	Reg. No. 39,833
Frederick M. Fliegel	Reg. No. 36,138
Donald Brent Kenady	Reg. No. 40,045
James E. Lake	Reg. No. 44,854
Bernard Berman	Reg. No. 37,279
Jennifer J. Taylor, Ph.D.	Reg. No. P 48,711

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and also attorneys Michael L. Lynch (Reg. No. 30,871) and Charles B. Brantley II (Reg. No. 38,086) of Micron Technology, Inc., as its attorneys with full power of substitution to prosecute this application and transact all business in the Patent and Trademark Office connected therewith.

The Assignee certifies that the above-identified Assignment has been reviewed and to the best of Assignee's knowledge and belief, title is in the Assignee, and a copy of the Assignment is submitted herewith.

Please direct all correspondence regarding this application to:

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MICRON TECHNOLOGY, INC.

Dated: 7-29-01

By: 

Name: Michael L. Lynch, Esq.
Title: Chief Patent Counsel

Attachment: Copy of Assignment; Copy of Board of Directors' Resolution

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